EE330 Spring 2018 HW13 Solutions TA: George Alphonse

Problem 1:

$$V_{TRIP} = \frac{(V_{Tn}) + (V_{DD} + V_{Tp}) * \sqrt{\left(\frac{u_p}{u_n}\right)\left(\frac{W_2}{W_1}\right)\left(\frac{L_1}{L_2}\right)}}{1 + \sqrt{\left(\frac{u_p}{u_n}\right)\left(\frac{W_2}{W_1}\right)\left(\frac{L_1}{L_2}\right)}} = \frac{(0.5) + (2.05 - 0.5) * \sqrt{\left(\frac{70}{350}\right)\left(\frac{1}{1}\right)\left(\frac{1}{1}\right)}}{1 + \sqrt{\left(\frac{70}{350}\right)\left(\frac{1}{1}\right)\left(\frac{1}{1}\right)}}$$

$$= 0.824 \text{ V}$$

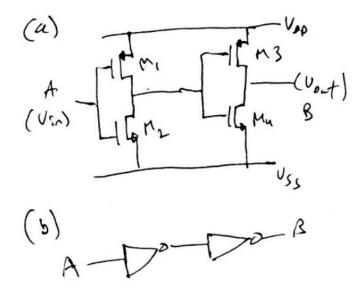
Problem 2:

$$V_{TRIP} = \frac{0.4 \ V \ and \ V_{Tp} = -0.6 \ V}{1 + \left(\frac{70}{350}\right)\left(\frac{1}{1}\right)\left(\frac{1}{1}\right)} = 0.724 \ V$$

$$Percent \ Deviation = \frac{0.824 - 0.724}{0.824} = 12.1\%$$

Problem 3:

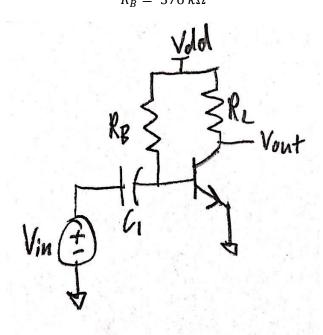
Problem 4:



Problem 5:

Assume C_1 is large, and set VDD = 10V

$$I_{C} = \frac{V_{DD} - V_{outQ}}{R_{L}} = \beta_{n}I_{B} = 100 * \frac{V_{DD} - 0.6V}{R_{B}}$$
$$\frac{10V - 5V}{2k\Omega} = 100 * \frac{10V - 0.6V}{R_{B}}$$
$$R_{B} = 376 k\Omega$$



Problem 6:

$$\frac{I_{out} + I_{BO}}{I_{in} + I_{BS}} = \frac{A_{EO1}}{A_{EO0}} = 5$$

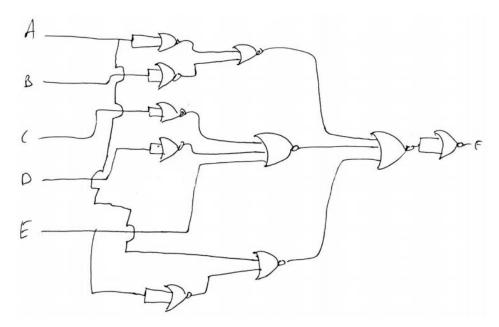
$$I_{out} + I_{BO} = 5I_{in} + 5I_{BS}$$

$$I_{out} = 5I_{in} + (5I_{BS} - I_{BO}) = 5I_{in}$$

Problem 7:

a.)
$$F = AB + CD\bar{E} + \bar{A}E$$

c.)
$$F = \overline{A}\overline{B} + \overline{C} + \overline{D} + E + A + \overline{E}$$



e.) Just replace all NOR gates in above schematic with transistor level NOR gate

